Bus buffer/line driver; 3-state

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1. General description

The 74HC1G126 and 74HCT1G126 are high-speed, Si-gate CMOS devices. They provide one non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input pin (OE). A LOW at pin OE causes the output as assume a high-impedance OFF-state.

The HC device has CMOS input switching levels and supply voltage range 2 V to 6 V.

The HCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

The bus driver output currents are equal to those of the 74HC126 and 74HCT126.

2. Features

- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- SOT353-1 and SOT753 package options

3. Ordering information

Table 1. Ordering information								
Type number	Package							
	Temperature range	Name	Description	Version				
74HC1G126GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads;	SOT353-1				
74HCT1G126GW			body width 1.25 mm					
74HC1G126GV	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753				
74HCT1G126GV								

4. Marking

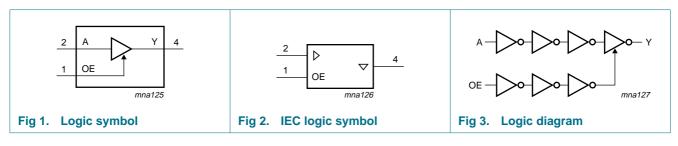
Table 2.Marking codes

Type number	Marking
74HC1G126GW	HN
74HCT1G126GW	TN
74HC1G126GV	H26
74HCT1G126GV	T26

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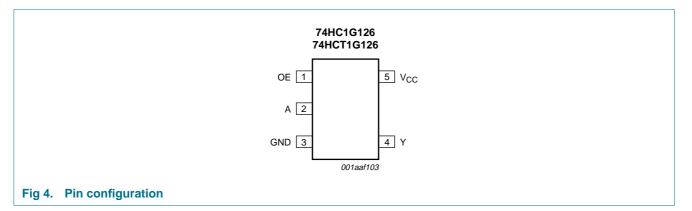
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5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
OE	1	output enable input
А	2	data input
GND	3	ground (0 V)
Y	4	data output
V _{CC}	5	supply voltage

7. Functional description

Table 4.Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state

Inputs OE		Output
OE	A	Y
н	L	L
Н	Н	Н
L	Х	Z

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V). [1]

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V_{I} < -0.5 V or V_{I} > V_{CC} + 0.5 V	-	±20	mA
Ι _{ΟΚ}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
lo	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±35.0	mA
I _{CC}	supply current		-	70	mA
I _{GND}	ground current		-70	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C$ to +125 $^{\circ}C$	[2] _	200	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] Above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74	74HC1G126			74HCT1G126		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
	and fall rate	$V_{CC} = 4.5 V$	-	-	139	-	-	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

0	,	, ,,	uno					
Symbol	Parameter	Conditions	-40	–40 °C to +85 °C			–40 °C to +125 °C	
			Min	Тур	Max	Min	Max	
For type 7	74HC1G126							
V _{IH} HI	HIGH-level input	$V_{CC} = 2.0 V$	1.5	1.2	-	1.5	-	V
	voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	V
		$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	V

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Symbol	Parameter	Conditions	–40 °C to +85 °C			_40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	
V _{он}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	2.0	-	1.9	-	V
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	4.32	-	3.7	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	5.81	-	5.2	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	V
		I_{O} = 6.0 mA; V_{CC} = 4.5 V	-	0.15	0.33	-	0.4	V
		I_{O} = 7.8 mA; V_{CC} = 6.0 V	-	0.16	0.33	-	0.4	V
I _I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	1.0	-	1.0	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or}$ GND; $V_{CC} = 6.0 \text{ V}$	-	-	5	-	10	μA
lcc	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 6.0 \ V \end{array}$	-	-	10	-	20	μA
Cı	input capacitance		-	1.5	-	-	-	pF
For type 7	74HCT1G126							
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$						
	voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	V
		$I_{O} = -6.0 \text{ mA}$	3.84	4.32	-	3.7	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$						
	voltage	I _O = 20 μA	-	0	0.1	-	0.1	V
		I _O = 6.0 mA	-	0.16	0.33	-	0.4	V
lı	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	1.0	-	1.0	μΑ
l _{oz}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = V_{CC} \text{ or}$ GND; $V_{CC} = 5.5 \text{ V}$	-	-	5	-	10	
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	10	-	20	μA
ΔI _{CC}	additional supply current	per input; $V_{CC} = 4.5$ V to 5.5 V; $V_I = V_{CC} - 2.1$ V; $I_O = 0$ A	-	-	500	-	850	μΑ
CI	input capacitance		-	1.5	-	-	-	pF

Table 7. Static characteristics ... continued

11. Dynamic characteristics

Table 8. Dynamic characteristics

GND = 0 V; $t_r = t_f \le 6.0 \text{ ns}$; $C_L = 50 \text{ pF}$ unless otherwise specified. All typical values are measured at $T_{amb} = 25 \text{ °C}$. For test circuit see Figure 7

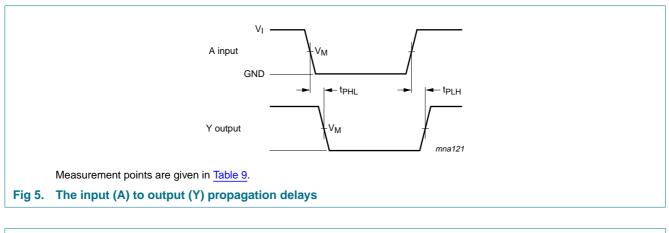
Symbol	Parameter	Conditions		–40 °C to +85 °C			–40 °C t	o +125 °C	Unit
				Min	Тур	Max	Min	Max	1
For type	74HC1G126								
t _{pd}	propagation delay	A to Y; see Figure 5	<u>[1]</u>						
		$V_{CC} = 2.0 V$		-	24	125	-	150	ns
		$V_{CC} = 4.5 V$		-	10	25	-	30	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	9	-	-	-	ns
		$V_{CC} = 6.0 V$		-	9	21	-	26	ns
t _{en}	enable time	OE to Y; see Figure 6	[1]						
		$V_{CC} = 2.0 V$		-	24	155	-	190	ns
		$V_{CC} = 4.5 V$		-	10	31	-	38	ns
		$V_{CC} = 6.0 V$		-	8	26	-	32	ns
t _{dis}	disable time	OE to Y; see Figure 6	[1]						
		$V_{CC} = 2.0 V$		-	16	155	-	190	ns
		$V_{CC} = 4.5 V$		-	12	31	-	38	ns
		$V_{CC} = 6.0 V$		-	11	26	-	32	ns
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC}	[2]	-	30	-	-	-	pF
For type	e 74HCT1G126								
t _{pd}	propagation delay	A to Y; see Figure 5	[1]						
		$V_{CC} = 4.5 V$		-	11	30	-	36	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	10	-	-	-	ns
t _{en}	enable time	OE to Y; see Figure 6; V_{CC} = 4.5 V	<u>[1]</u>	-	10	35	-	42	ns
t _{dis}	disable time	OE to Y; see Figure 6; V_{CC} = 4.5 V	<u>[1]</u>	-	12	31	-	38	ns
C _{PD}	power dissipation capacitance	V_{I} = GND to V_{CC} – 1.5 V	[2]	-	27	-	-	-	pF

- $\begin{array}{ll} \mbox{[2]} & C_{PD} \mbox{ is used to determine the dynamic power dissipation P_D (μW). \\ & P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum \left(C_L \times V_{CC}{}^2 \times f_o \right) \mbox{ where:} \\ & f_i = \mbox{ input frequency in MHz} \\ & f_o = \mbox{ output frequency in MHz} \\ & C_L = \mbox{ output load capacitance in pF} \end{array}$
 - V_{CC} = supply voltage in Volts

 $\Sigma (C_L \times V_{CC}^2 \times f_o) = sum of outputs$

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12. Waveforms



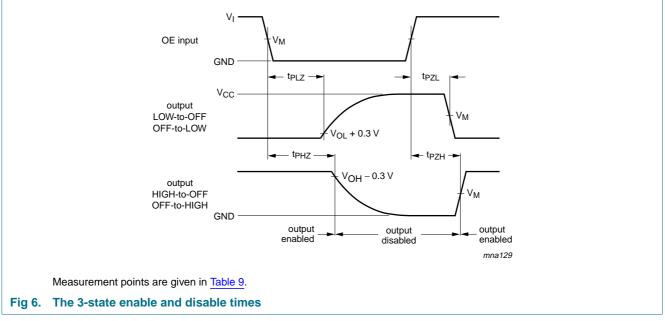


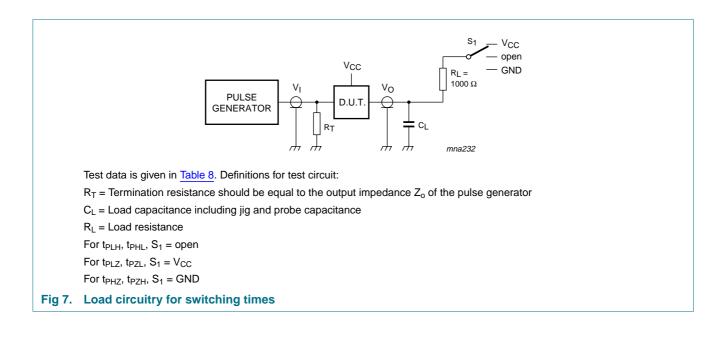
Table 9.Measurement points

Туре	• • • • • • • • • • • • • • • • • • •		Output
			V _M
74HC1G126	$0.5 \times V_{CC}$	GND to V _{CC}	$0.5 \times V_{CC}$
74HCT1G126	1.3 V	GND to 3.0 V	1.3 V

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13. Package outline

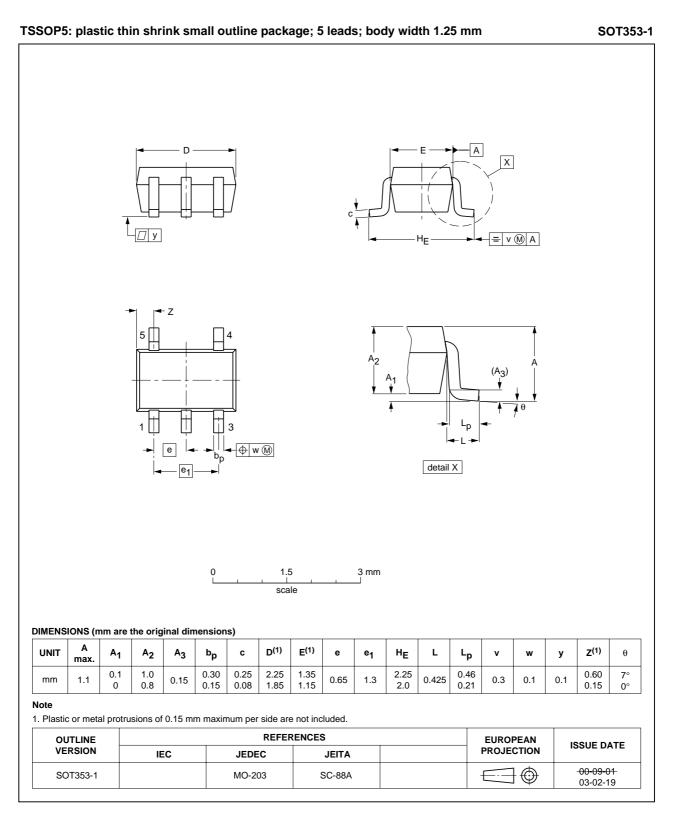


Fig 8. Package outline SOT353-1 (TSSOP5)

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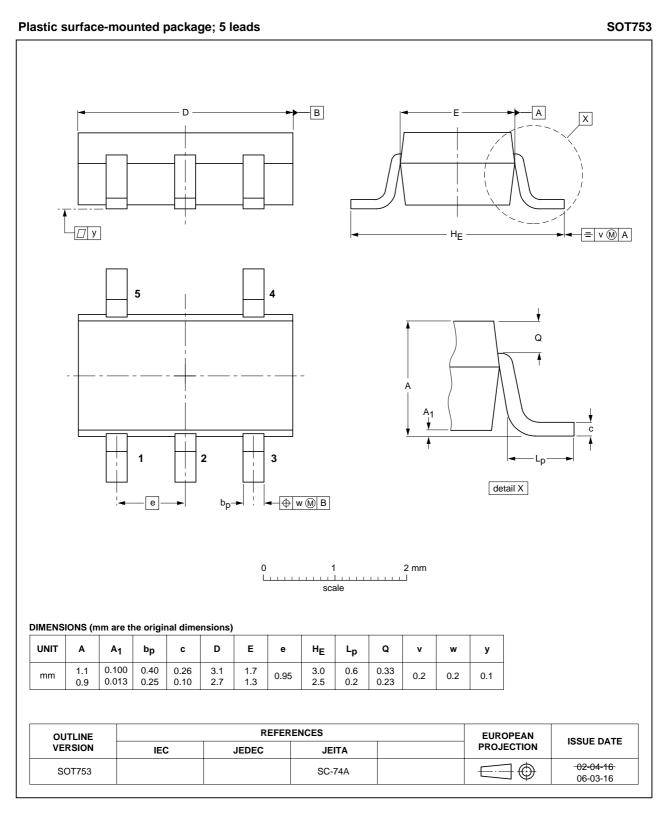


Fig 9. Package outline SOT753 (SC-74A)

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14. Abbreviations

Table 10.	able 10. Abbreviations				
Acronym	Description				
DUT	Device Under Test				
TTL	Transistor-Transistor Logic				

15. Revision history

Table 11.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT1G126_4	20070720	Product data sheet	-	74HC_HCT1G126_3			
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 						
	 Legal texts 	have been adapted to the new	w company name whe	ere appropriate.			
	 Package S 	OT353 changed to SOT353-1	in Table 1 and Figure	8.			
	 Quick Refe 	erence Data and Soldering sec	ctions removed.				
	Section 2 "	Features" updated.					
74HC_HCT1G126_3	20020515	Product specification	-	74HC_HCT1G126_2			
74HC_HCT1G126_2	20010406	Product specification	-	74HC_HCT1G126			
74HC_HCT1G126	19970924	Preliminary specification	-	-			

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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